

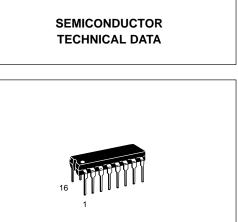
CRYSTAL OSCILLATOR



Crystal Oscillator

The MC12061 is for use with an external crystal to form a crystal controlled oscillator. In addition to the fundamental series mode crystal, two bypass capacitors are required (plus usual power supply pin bypass capacitors). Translators are provided internally for MECL and TTL outputs.

- Frequency Range = 2.0 to 20 MHz
- Temperature Range = 0 to + 70°C
- Single Supply Operation: +5.0 Vdc or -5.2 Vdc
- Three Outputs Available:
 - 1. Complementary Sine Wave (600 mVpp typ)
 - 2. Complementary MECL
 - 3. Single Ended TTL



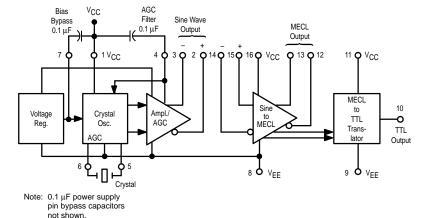


Figure 1. Block Diagram

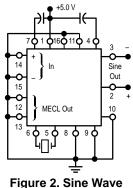
P SUFFIX PLASTIC PACKAGE CASE 648

ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC12061P	$T_A = 0^\circ$ to +70°C	Plastic

TYPICAL CIRCUIT CONFIGURATIONS

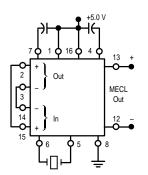
Note: 0.1 µF power supply pin bypass capacitors not shown.



Output

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Figure 3. MTTL Output



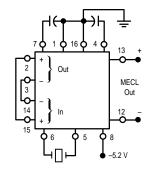


Figure 4. MECL Output (+5.0 V Supply)

Figure 5. MECL Output (-5.2 V Supply)

CRYSTAL REQUIREMENTS Note: Start-up stabilization time is a function of crystal series resis-

time is a function of crystal series resistance. The lower the resistance, the faster the circuit stabilizes. CharacteristicMC12061Mode of OperationFundamental Series ResonanceFrequency Range2.0 MHz - 20 MHzSeries Resistance, R1Minimum at FundamentalMaximum Effective Resistance R_{E(max)}155 ohms

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ELECTRICAL CHARACTERISTICS

			Test Limits								
Characteristic		Pin Under	0	°C		+25°C		+7	-		
	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Unit	
Power Supply Drain Current	ICC	1	_	_	13	16	19	_	_	mAdc	
		1 11 16	- - -	- - -	18 - 13	23 3.0 16	28 4.0 19	- - -	_ _ _		
Input Current	l _{inH}	14 15	_ _	-	_ _	_ _	250 250	_ _	-	μAdc	
	l _{inL}	14 15	-	-	-	-	1.0 1.0	-		μAdc	
Differential Offset Voltage	ΔV	4 to 7 2 to 3		-	40 -200	_ 0	325 +200		-	mAdc	
Output Voltage Level	Vout	2 3				3.5 3.5	_ _			Vdc	
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	4.0 4.0	4.16 4.16	4.04 4.04		4.19 4.19	4.1 4.1	4.28 4.28	Vdc	
	V _{OH2}	10	2.4	-	2.4	-	-	2.4	-		
Logic '0' Output Voltage	VOL1 (Note 1)	12 13	2.98 2.98	3.43 3.43	3.0 3.0		3.44 3.44	3.02 3.02	3.47 3.47	Vdc	
	VOL2	10 10		0.5 0.5			0.5 0.5		0.5 0.5		
Logic '1' Threshold Voltage	VOHA	12 13	3.98 3.98	-	4.02 4.02		_ _	4.08 4.08	-	Vdc	
Logic '0' Threshold Voltage	VOLA	12 13	-	3.45 3.45			3.46 3.46	-	3.49 3.49	Vdc	
Output Short Circuit Current	IOS	10	20	60	20	-	60	20	60	mAdc	

NOTE: 1. Devices will meet standard MECL logic levels using $V_{EE} = -5.2$ Vdc and $V_{CC} = 0$.

ELECTRICAL CHARACTERISTICS (continued)

				TEST V	OLTAGE/CU	JRRENT VAI	LUES		
					Volt	S			
	@ Test Temp	erature	VIHmax	V _{ILmin}	VIHT	VCCL]		
		0°C	4.16	3.19	3.86	3.51	4.0	4.75	
		+25°C	4.19	3.21	3.90	3.52	4.0	4.75	
		+75°C	4.28	3.23	3.96	3.55	4.0	4.75	
		Pin Under	TE	ST VOLTAGE	APPLIED	TO PINS LIS		w	
Characteristic	Symbol	Test	V _{IHmax}	v _{ILmin}	V _{IHAmin}	V _{ILAmax}	VIHT	V _{CCL}	Gnd
Power Supply Drain Current	ICC	1	-	-	-	-	-	-	8
		1 11 16	- 14 -	- 15 -		- - -		_ _ _	8 8,9 8
Input Current	linH	14 15	14 15	15 14					8 8
	linL	14 15	15 14						8,14 8,15
Differential Offset Voltage	ΔV	4 to 7 2 to 3		-			5,6 4	-	8 -
Output Voltage Level	Vout	2 3		-			4 4		8 8
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	14 15	15 14			-		8 8
	VOH2	10	15	14	-	-	_	11,16	8,9
Logic '0' Output Voltage	VOL1 (Note 1)	12 13	15 14	14 15					8 8
	V _{OL2}	10 10	14 14	15 15			-	11,16 _	8,9 8,9
Logic '1' Threshold Voltage	Voha	12 13		-	14 15	15 14	-		8 8
Logic '0' Threshold Voltage	VOLA	12 13		_	15 14	14 15	-		8 8
Output Short Circuit Current	los	10	15	14	-	-	-	11,16	8,9,10

NOTE: 1. Devices will meet standard MECL logic levels using $V_{EE} = -5.2Vdc$ and $V_{CC} = 0$.

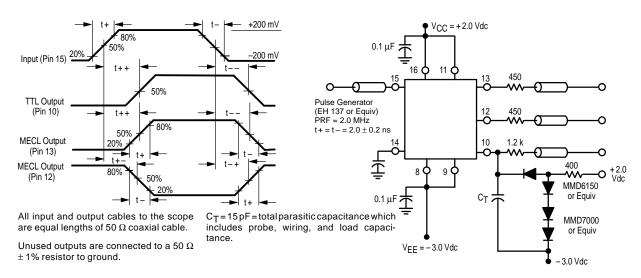
ELECTRICAL CHARACTERISTICS (continued)

			TEST VOLTAGE/CURRENT VALUES							
			V	olts		mA				
	@ Test Temp	perature	Vcc	VCCH	lol	ЮН	١ _{IL}			
		0°C	5.0	5.25	16	-0.4	-2.5			
		+25°C	5.0	5.25	16	-0.4	-2.5			
	5.0	5.25	16	-0.4	-2.5					
		Pin	TEST	VOLTAGE API		IS LISTED BE	LOW			
Characteristic	Symbol	Under Test	v _{cc}	VCCH	IOL	ЮН	۱ _{IL}	Gnd		
Power Supply Drain Current	ICC	1	1	-	-	-	-	8		
		1 11 16	1 11,16 16				_ _ _	8 8,9 8		
Input Current	linH	14 15	16 16					8 8		
	linL	14 15	16 16					8,14 8,15		
Differential Offset Voltage	ΔV	4 to 7 2 to 3	1 -					8		
Output Voltage Level	Vout	2 3	1 1					8 8		
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	16 16				12 13	8 8		
	VOH2	10	_	_	_	10	-	8,9		
Logic '0' Output Voltage	V _{OL1} (Note 1)	12 13	16 16				12 13	8 8		
	V _{OL2}	10 10	-	_ 11,16	10 10			8,9 8,9		
Logic '1' Threshold Voltage	VOHA	12 13	16 16	-			12 13	8 8		
Logic '0' Threshold Voltage	VOLA	12 13	16 16	-			12 13	8 8		
Output Short Circuit Current	IOS	10	_	_	_	_	_	8,9,10		

NOTE: 1. Devices will meet standard MECL logic levels using $V_{EE} = -5.2Vdc$ and $V_{CC} = 0$.

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Figure 6. AC Characteristics – MECL and TTL Outputs



		Test Limits							TEST VOLTAGES/WAVEFORMS APPLIED TO PINS LISTED BELOW:						
		Pin Under	0	°C		+25°C	;	+7	5°C						
Characteristic	Symbol	Test	Min	Max	Min	Тур	Мах	Min	Max	Unit	Pulse In	Pulse Out	+2.0 Vdc	-3.0 Vdc	Gnd
Propagation Delay	$t_{15+10+} \\ t_{15-10-} \\ t_{15+12-} \\ t_{15-12+} \\ t_{15+13+} \\ t_{15-13-} \\ t_{15-13-1} \\ t_{15-$	10 10 12 12 13 13		22 19 5.2 5.0 4.8 5.0		17 12 4.3 3.7 4.0 4.0	25 18 5.5 5.2 5.0 5.0		27 18 5.8 5.2 5.2 5.2 5.1	ns	15	10 10 12 12 13 13	11,16	8,9	14
Rise Time	^t 12+ ^t 13+	12 13	_	4.0 4.0	_	3.0 3.0	4.0 4.0	—	4.4 4.4	ns ns	15 15	12 13	11,16 11,16	8,9 8,9	14 14
Fall Time	t ₁₂ - t ₁₃ -	12 13	_	4.0 4.0	_	3.0 3.0	4.0 4.0	_	4.0 4.0	ns ns	15 15	12 13	11,16 11,16	8,9 8,9	14 14

	Pin Under	+25°C			TEST VOLTA TO PINS LIS	
Characteristic	Test	Min	Тур	Unit	+2.0 Vdc	-3.0 Vdc
Sine Wave Amplitude						
	2	650	750	mVp-p	1	8,9
	3	650	750			

Figure 7. AC Test Circuit – Sine Wave Output

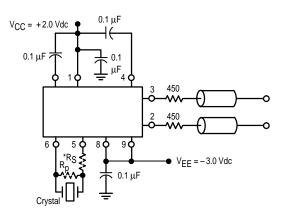
All output cables to the scope are equal lengths of 50 Ω coaxial cable. All unused cables must be terminated with a 50 Ω \pm 1% resistor to ground.

 $450\,\Omega$ resistor and the scope termination impedance constitute a 10:1 attenuator probe.

Crystal — Reeves Hoffman Series Mode,

- Series Resistance Minimum at Fundamental f = 10 MHz
 - $R_E = 5 \Omega$
- $\label{eq:RS} \ensuremath{^*\text{RS}}\xspace = 15 \ensuremath{\,k\Omega}\xspace$ is inserted only for test purposes. When used with the above specified crystal, it guarantees oscillation with any crystal which has an equivalent series resistance $\leqslant 155 \ensuremath{\,\Omega}\xspace$

 R_p : will improve start up problems value: 200–500 Ω



MC12061 OPERATING CHARACTERISTICS

The MC12061 consists of three basic sections: an oscillator with AGC and two translators (NO TAG). Buffered complementary sine wave outputs are available from the oscillator section. The translators convert these sine wave outputs to levels compatible with MECL and/or TTL.

Series mode crystals should be used with the oscillator. If it is necessary or desirable to adjust the crystal frequency, a reactive element can be inserted in series with the crystal an inductor to lower the frequency or a capacitor to raise it. When such an adjustment is necessary, it is recommended that the crystal be specified slightly lower in frequency and a series trimmer capacitor be added to bring the oscillator back on frequency. As the oscillator frequency is changed from the natural resonance of the crystal, more and more dependence is placed on the external reactance, and temperature drift of the trimming components then affects overall oscillator performance.

The MC12061 is designed to operate from a single supply — either +5.0 Vdc or -5.2 Vdc. Although each translator has separate V_{CC} and V_{EE} supply pins, the circuit is NOT designed to operate from both voltage levels at the same time. The separate V_{EE} pin from the TTL translator helps minimize transient disturbance. If neither translator is being used, all unused pins (9 thru 16) should be connected to V_{EE} (pin 8). With the translators not powered, supply current drain is typically reduced from 42 mA to 23 mA for the MC12061.

Frequency Stability

Output frequency of different oscillator circuits (of a given device type number) will vary somewhat when used with a given test setup. However, the variation should be within approximately $\pm 0.001\%$ from unit to unit.

Frequency variations with temperature (independent of the crystal, which is held at 25°C) are small — about – 0.08 ppm/°C for MC12061 operating at 8.0 MHz (see NO TAG).

Signal Characteristics

The sine wave outputs at either pin 2 or pin 3 will typically range from 800 mV_{p-p} (no load) to 500 mV_{p-p} (120 ohm ac load). Approximately 500 mV_{p-p} can be provided across 50 ohms by slightly increasing the dc current in the output buffer by the addition of an external resistor (680 ohms) from pin 2 or 3 to ground, as shown in Figure 9. Frequency drift is typically less than 0.0003% when going from a high-impedance load (1 megohm, 15 pF) to the 50 ohm load of Figure 9. The dc voltage level at pin 2 or 3 is nominally 3.5 Vdc with V_{CC} = +5.0 Vdc.

Harmonic distortion content in the sine wave outputs is crystal as well as circuit dependent. The largest harmonic (third) will usually be at least 15 dB down from the fundamental. The harmonic content is approximately load independent except that the higher harmonic levels (greater than the fifth) are increased when the MECL translator is being driven.

Typically, the MECL outputs (pins 12 and 13) will drive up to five gates, as defined in NO TAG, and the TTL output (pin 10) will drive up to ten gates, as defined in NO TAG.

Noise Characteristics

Noise level evaluation of the sine wave outputs using the circuit of NO TAG, with operation at or 9.0 MHz, indicates the following characteristics:

- Noise floor (200 kHz from oscillator center frequency) is approximately –122 dB when referenced to a 1.0 Hz bandwidth. Noise floor is not sensitive to load conditions and/or translator operation.
- Close-in noise (100 Hz from oscillator center frequency) is approximately –88 dB when referenced to a 1.0 Hz bandwidth.

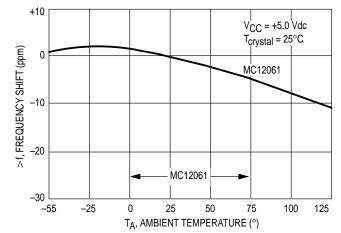
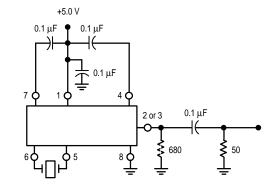


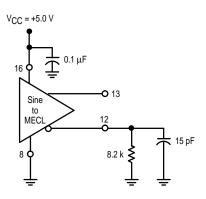
Figure 8. Frequency Variation Due to Temperature

Figure 9. Driving Low Impedance Loads



* See text under signal characteristics.

Figure 10. MECL Translator Load Capability



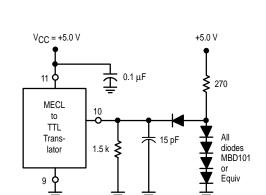
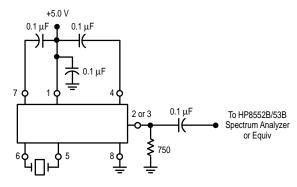


Figure 11. TTL Translator Load Capability

Figure 12. Noise Measurement Test Circuit

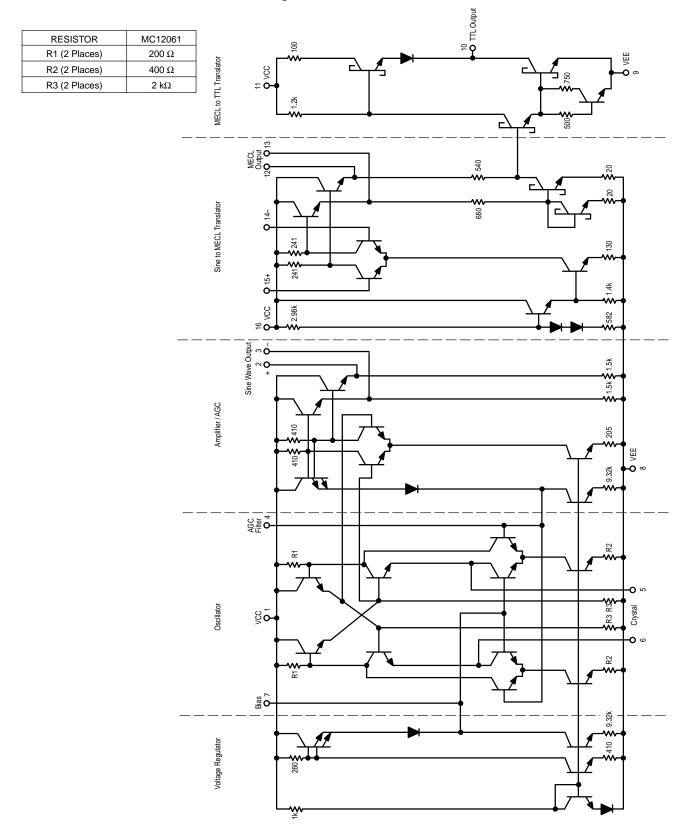


ANALYZER SETTING

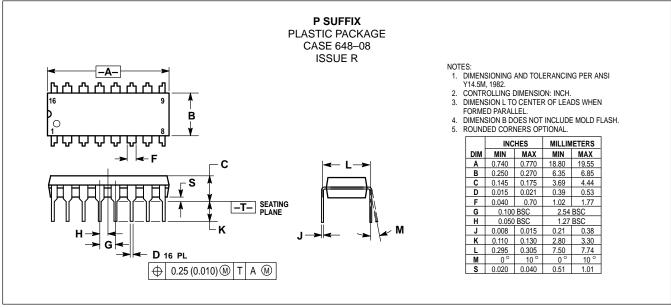
Measurement	Sweep	Bandwidth	Video Filter
Noise Floor	50 kHz/div	10 kHz	10 Hz
Close-In Noise	20 kHz/div	10 Hz	10 Hz

MOTOROLA RF/IF DEVICE DATA

Figure 13. Circuit Schematic



OUTLINE DIMENSIONS



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